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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Obsolete
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	72MHz
Connectivity	I ² C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	28
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4.25K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 20x14b; D/A 4x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	32-UFQFN Exposed Pad
Supplier Device Package	32-QFN (4x4)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8lb12f64es0-b-qfn32

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

1. Feature List

The EFM8LB1 device family are fully integrated, mixed-signal system-on-a-chip MCUs. Highlighted features are listed below.

- Core:
 - Pipelined CIP-51 Core
 - · Fully compatible with standard 8051 instruction set
 - 70% of instructions execute in 1-2 clock cycles
 - 72 MHz maximum operating frequency
- Memory:
 - Up to 64 kB flash memory (63 kB user-accessible), in-system re-programmable from firmware in 512-byte sectors
 - Up to 4352 bytes RAM (including 256 bytes standard 8051 RAM and 4096 bytes on-chip XRAM)
- · Power:
 - Internal LDO regulator for CPU core voltage
 - · Power-on reset circuit and brownout detectors
- I/O: Up to 29 total multifunction I/O pins:
 - Up to 25 pins 5 V tolerant under bias
 - Selectable state retention through reset events
 - · Flexible peripheral crossbar for peripheral routing
 - 5 mA source, 12.5 mA sink allows direct drive of LEDs
- · Clock Sources:
 - Internal 72 MHz oscillator with accuracy of ±2%
 - Internal 24.5 MHz oscillator with ±2% accuracy
 - · Internal 80 kHz low-frequency oscillator
 - External CMOS clock option
 - External crystal/RC oscillator (up to 25 MHz)

- Analog:
 - 14/12/10-Bit Analog-to-Digital Converter (ADC)
 - Internal calibrated temperature sensor (±3 °C)
 - 4 x 12-Bit Digital-to-Analog Converters (DAC)
 - 2 x Low-current analog comparators with adjustable reference
- Communications and Digital Peripherals:
 - 2 x UART, up to 3 Mbaud
 - SPI™ Master / Slave, up to 12 Mbps
 - SMBus™/I2C™ Master / Slave, up to 400 kbps
 - I²C High-Speed Slave, up to 3.4 Mbps
 - 16-bit CRC unit, supporting automatic CRC of flash at 256byte boundaries
 - 4 Configurable Logic Units
- · Timers/Counters and PWM:
 - 6-channel Programmable Counter Array (PCA) supporting PWM, capture/compare, and frequency output modes
 - 6 x 16-bit general-purpose timers
 - Independent watchdog timer, clocked from the low frequency oscillator
- On-Chip, Non-Intrusive Debugging
 - · Full memory and register inspection
 - Four hardware breakpoints, single-stepping
- Pre-programmed UART or SMBus bootloader

With on-chip power-on reset, voltage supply monitor, watchdog timer, and clock oscillator, the EFM8LB1 devices are truly standalone system-on-a-chip solutions. The flash memory is reprogrammable in-circuit, providing nonvolatile data storage and allowing field upgrades of the firmware. The on-chip debugging interface (C2) allows non-intrusive (uses no on-chip resources), full speed, in-circuit debugging using the production MCU installed in the final application. This debug logic supports inspection and modification of memory and registers, setting breakpoints, single stepping, and run and halt commands. All analog and digital peripherals are fully functional while debugging. Device operation is specified from 2.2 V up to a 3.6 V supply. Devices are AEC-Q100 qualified (pending) and available in 4x4 mm 32-pin QFN, 3x3 mm 24-pin QFN, 32-pin QFP, or 24-pin QSOP packages. All package options are lead-free and RoHS compliant.

3.2 Power

All internal circuitry draws power from the VDD supply pin. External I/O pins are powered from the VIO supply voltage (or VDD on devices without a separate VIO connection), while most of the internal circuitry is supplied by an on-chip LDO regulator. Control over the device power can be achieved by enabling/disabling individual peripherals as needed. Each analog peripheral can be disabled when not in use and placed in low power mode. Digital peripherals, such as timers and serial buses, have their clocks gated off and draw little power when they are not in use.

Table 3.1. Power Modes

Power Mode	Details	Mode Entry	Wake-Up Sources
Normal	Core and all peripherals clocked and fully operational		
ldle	 Core halted All peripherals clocked and fully operational Code resumes execution on wake event 	Set IDLE bit in PCON0	Any interrupt
Suspend	 Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulator in normal bias mode for fast wake Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event 	 Switch SYSCLK to HFOSC0 Set SUSPEND bit in PCON1 	 Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Falling Edge CLUn Interrupt-Enabled Event
Stop	 All internal power nets shut down Pins retain state Exit on any reset source 	1. Clear STOPCF bit in REG0CN 2. Set STOP bit in PCON0	Any reset source
Snooze	 Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulator in low bias current mode for energy savings Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event 	 Switch SYSCLK to HFOSC0 Set SNOOZE bit in PCON1 	 Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Falling Edge CLUn Interrupt-Enabled Event
Shutdown	 All internal power nets shut down Pins retain state Exit on pin or power-on reset 	1. Set STOPCF bit in REG0CN 2. Set STOP bit in PCON0	RSTb pin resetPower-on reset

3.3 I/O

Digital and analog resources are externally available on the device's multi-purpose I/O pins. Port pins P0.0-P2.3 can be defined as general-purpose I/O (GPIO), assigned to one of the internal digital resources through the crossbar or dedicated channels, or assigned to an analog function. Port pins P2.4 to P3.7 can be used as GPIO. Additionally, the C2 Interface Data signal (C2D) is shared with P3.0 or P3.7, depending on the package option.

The port control block offers the following features:

- Up to 29 multi-functions I/O pins, supporting digital and analog functions.
- · Flexible priority crossbar decoder for digital peripheral assignment.
- Two drive strength settings for each port.
- State retention feature allows pins to retain configuration through most reset sources.
- Two direct-pin interrupt sources with dedicated interrupt vectors (INT0 and INT1).
- Up to 24 direct-pin interrupt sources with shared interrupt vector (Port Match).

3.4 Clocking

The CPU core and peripheral subsystem may be clocked by both internal and external oscillator resources. By default, the system clock comes up running from the 24.5 MHz oscillator divided by 8.

The clock control system offers the following features:

- Provides clock to core and peripherals.
- 24.5 MHz internal oscillator (HFOSC0), accurate to ±2% over supply and temperature corners.
- 72 MHz internal oscillator (HFOSC1), accurate to ±2% over supply and temperature corners.
- 80 kHz low-frequency oscillator (LFOSC0).
- External RC, CMOS, and high-frequency crystal clock options (EXTCLK).
- · Clock divider with eight settings for flexible clock scaling:
 - Divide the selected clock source by 1, 2, 4, 8, 16, 32, 64, or 128.
 - HFOSC0 and HFOSC1 include 1.5x pre-scalers for further flexibility.

3.5 Counters/Timers and PWM

Programmable Counter Array (PCA0)

The programmable counter array (PCA) provides multiple channels of enhanced timer and PWM functionality while requiring less CPU intervention than standard counter/timers. The PCA consists of a dedicated 16-bit counter/timer and one 16-bit capture/compare module for each channel. The counter/timer is driven by a programmable timebase that has flexible external and internal clocking options. Each capture/compare module may be configured to operate independently in one of five modes: Edge-Triggered Capture, Software Timer, High-Speed Output, Frequency Output, or Pulse-Width Modulated (PWM) Output. Each capture/compare module has its own associated I/O line (CEXn) which is routed through the crossbar to port I/O when enabled.

- 16-bit time base
- Programmable clock divisor and clock source selection
- · Up to six independently-configurable channels
- 8, 9, 10, 11 and 16-bit PWM modes (center or edge-aligned operation)
- Output polarity control
- Frequency output mode
- · Capture on rising, falling or any edge
- · Compare function for arbitrary waveform generation
- · Software timer (internal compare) mode
- · Can accept hardware "kill" signal from comparator 0 or comparator 1

Universal Asynchronous Receiver/Transmitter (UART1)

UART1 is an asynchronous, full duplex serial port offering a variety of data formatting options. A dedicated baud rate generator with a 16-bit timer and selectable prescaler is included, which can generate a wide range of baud rates. A received data FIFO allows UART1 to receive multiple bytes before data is lost and an overflow occurs.

UART1 provides the following features:

- · Asynchronous transmissions and receptions
- Dedicated baud rate generator supports baud rates up to SYSCLK/2 (transmit) or SYSCLK/8 (receive)
- 5, 6, 7, 8, or 9 bit data
- Automatic start and stop generation
- Automatic parity generation and checking
- · Single-byte buffer on transmit and receive
- Auto-baud detection
- · LIN break and sync field detection
- CTS / RTS hardware flow control

Serial Peripheral Interface (SPI0)

The serial peripheral interface (SPI) module provides access to a flexible, full-duplex synchronous serial bus. The SPI can operate as a master or slave device in both 3-wire or 4-wire modes, and supports multiple masters and slaves on a single SPI bus. The slave-select (NSS) signal can be configured as an input to select the SPI in slave mode, or to disable master mode operation in a multi-master environment, avoiding contention on the SPI bus when more than one master attempts simultaneous data transfers. NSS can also be configured as a firmware-controlled chip-select output in master mode, or disable to reduce the number of pins required. Additional general purpose port I/O pins can be used to select multiple slave devices in master mode.

- Supports 3- or 4-wire master or slave modes
- · Supports external clock frequencies up to 12 Mbps in master or slave mode
- · Support for all clock phase and polarity modes
- 8-bit programmable clock rate (master)
- Programmable receive timeout (slave)
- · Two byte FIFO on transmit and receive
- · Can operate in suspend or snooze modes and wake the CPU on reception of a byte
- · Support for multiple masters on the same data lines

System Management Bus / I2C (SMB0)

The SMBus I/O interface is a two-wire, bi-directional serial bus. The SMBus is compliant with the System Management Bus Specification, version 1.1, and compatible with the I²C serial bus.

The SMBus module includes the following features:

- · Standard (up to 100 kbps) and Fast (400 kbps) transfer speeds
- · Support for master, slave, and multi-master modes
- Hardware synchronization and arbitration for multi-master mode
- · Clock low extending (clock stretching) to interface with faster masters
- · Hardware support for 7-bit slave and general call address recognition
- Firmware support for 10-bit slave address decoding
- · Ability to inhibit all slave states
- Programmable data setup/hold times
- · Transmit and receive FIFOs (one byte) to help increase throughput in faster applications

3.10 Bootloader

All devices come pre-programmed with a UART0 bootloader or an SMBus bootloader. These bootloaders reside in the code security page, which is the last page of code flash; they can be erased if they are not needed.

The byte before the Lock Byte is the Bootloader Signature Byte. Setting this byte to a value of 0xA5 indicates the presence of the bootloader in the system. Any other value in this location indicates that the bootloader is not present in flash.

When a bootloader is present, the device will jump to the bootloader vector after any reset, allowing the bootloader to run. The bootloader then determines if the device should stay in bootload mode or jump to the reset vector located at 0x0000. When the bootloader is not present, the device will jump to the reset vector of 0x0000 after any reset.

More information about the bootloader protocol and usage can be found in *AN945: EFM8 Factory Bootloader User Guide*. Application notes can be found on the Silicon Labs website (www.silabs.com/8bit-appnotes) or within Simplicity Studio by using the [Application Notes] tile.

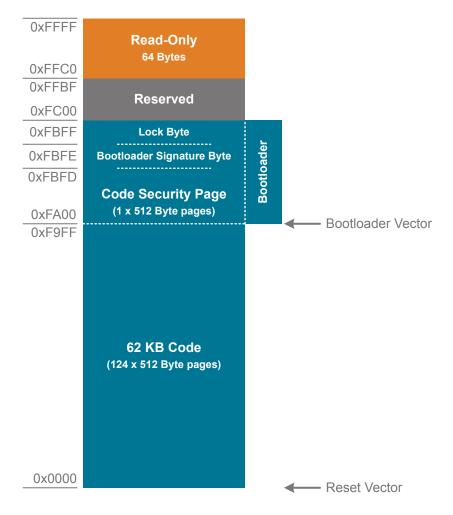


Figure 3.2. Flash Memory Map with Bootloader - 62.5 KB Devices

Table 3.2.	Summary	of Pins fo	or Bootloader	Communication
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Bootloader	Pins for Bootload Communication
UART	TX – P0.4
	RX – P0.5
SMBus	P0.2 – SDA ¹
	P0.3 – SCL ¹

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Power Supply Rejection Ratio	PSRR _{ADC}	At 1 kHz	_	66	_	dB
		At 1 MHz	_	43	_	dB
DC Performance	·		·			
Integral Nonlinearity	INL	14 Bit Mode	-3.5 ⁴	-1.2 / +5	8.5 ⁴	LSB
		12 Bit Mode	-1.9	-0.35 / +1	1.9	LSB
		10 Bit Mode	-0.6	±0.2	0.6	LSB
Differential Nonlinearity (Guaran-	DNL	14 Bit Mode	-14	±1	2.5 ⁴	LSB
teed Monotonic)		12 Bit Mode	-0.9	±0.3	0.9	LSB
		10 Bit Mode	-0.5	±0.2	0.5	LSB
Offset Error ⁵	E _{OFF}	14 Bit Mode	-84	-2.5	84	LSB
		12 Bit Mode	-2	0	2	LSB
		10 Bit Mode	-1	0	1	LSB
Offset Temperature Coefficient	TC _{OFF}		_	0.011	_	LSB/°C
Slope Error	E _M	14 Bit Mode	-15 ⁴	_	15 ⁴	LSB
		12 Bit Mode	-2.6	_	2.6	LSB
		10 Bit Mode	-1.1	_	1.1	LSB
Dynamic Performance 10 kHz Si	ne Wave Inp	ut 1 dB below full scale, Max thr	oughput, usin	g AGND pin		
Signal-to-Noise	SNR	14 Bit Mode	66 ⁴	72	_	dB
		12 Bit Mode	64	68	_	dB
		10 Bit Mode	59	61	_	dB
Signal-to-Noise Plus Distortion	SNDR	14 Bit Mode	66 ⁴	72	_	dB
		12 Bit Mode	64	68		dB
		10 Bit Mode	59	61	_	dB
Total Harmonic Distortion (Up to	THD	14 Bit Mode	_	-74	_	dB
5th Harmonic)		12 Bit Mode		-72	_	dB
		10 Bit Mode	_	-69	_	dB
Spurious-Free Dynamic Range	SFDR	14 Bit Mode		74	_	dB
		12 Bit Mode	_	74	_	dB
		10 Bit Mode	_	71	_	dB

Note:

1. This time is equivalent to four periods of a clock running at 18 MHz + 2%.

2. Conversion Time does not include Tracking Time. Total Conversion Time is:

Total Conversion Time = [RPT × (ADTK + NUMBITS + 1) × T(SARCLK)] + (T(ADCCLK) × 4)

where RPT is the number of conversions represented by the ADRPT field and ADCCLK is the clock selected for the ADC.

3. Absolute input pin voltage is limited by the $\ensuremath{\mathsf{V}_{\mathsf{IO}}}$ supply.

4. Measured with characterization data and not production tested.

5. The offset is determined using curve fitting since the specification is measured using linear search where the intercept is always positive.

4.1.10 Voltage Reference

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Internal Fast Settling Reference						
Output Voltage	V _{REFFS}		1.62	1.65	1.68	V
(Full Temperature and Supply Range)						
Temperature Coefficient	TC _{REFFS}		_	50	_	ppm/°C
Turn-on Time	t _{REFFS}		_	—	1.5	μs
Power Supply Rejection	PSRR _{REF} FS		—	400	_	ppm/V
On-chip Precision Reference	1					
Valid Supply Range	V _{DD}	1.2 V Output	2.2		3.6	V
		2.4 V Output	2.7	_	3.6	V
Output Voltage	V _{REFP}	1.2 V Output, V _{DD} = 3.3 V, T = 25 °C	1.195	1.2	1.205	V
		1.2 V Output	1.18	1.2	1.22	V
		2.4 V Output, V _{DD} = 3.3 V, T = 25 °C	2.39	2.4	2.41	V
		2.4 V Output	2.36	2.4	2.44	V
Turn-on Time, settling to 0.5 LSB	t _{VREFP}	4.7 μF tantalum + 0.1 μF ceramic bypass on VREF pin	—	3	_	ms
		0.1 μF ceramic bypass on VREF pin	—	100	_	μs
Load Regulation	LR _{VREFP}	VREF = 2.4 V, Load = 0 to 200 μ A to GND	—	8	_	μV/μΑ
		VREF = 1.2 V, Load = 0 to 200 μA to GND	—	5	_	μV/μΑ
Load Capacitor	C _{VREFP}	Load = 0 to 200 µA to GND	0.1	_	—	μF
Short-circuit current	ISC _{VREFP}		_		8	mA
Power Supply Rejection	PSRR _{VRE} FP		_	75	_	dB
External Reference						
Input Current	I _{EXTREF}	ADC Sample Rate = 1 Msps; VREF = 3.0 V	_	5	_	μΑ

Parameter	Symbol	Clocks
SMBus Operating Frequency	f _{SMB}	f _{CSO} / 3
Bus Free Time Between STOP and START Conditions	t _{BUF}	2 / f _{CSO}
Hold Time After (Repeated) START Condition	t _{HD:STA}	1 / f _{CSO}
Repeated START Condition Setup Time	t _{SU:STA}	2 / f _{CSO}
STOP Condition Setup Time	t _{SU:STO}	2 / f _{CSO}
Clock Low Period	t _{LOW}	1 / f _{CSO}
Clock High Period	t _{HIGH}	2 / f _{CSO}

Table 4.17. SMBus Peripheral Timing Formulas (Master Mode)

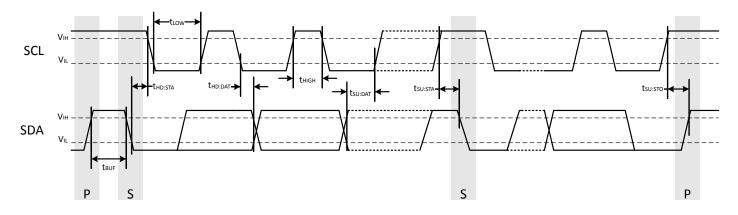


Figure 4.1. SMBus Peripheral Timing Diagram (Master Mode)

4.2 Thermal Conditions

Table 4.18. Thermal Conditions

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Thermal Resistance	θ _{JA}	QFN24 Packages	_	30	—	°C/W	
		QFN32 Packages	—	26	_	°C/W	
		QFP32 Packages	—	80	_	°C/W	
		QSOP24 Packages	_	65	—	°C/W	
Note:							

1. Thermal resistance assumes a multi-layer PCB with any exposed pad soldered to a PCB pad.

4.3 Absolute Maximum Ratings

Stresses above those listed in Table 4.19 Absolute Maximum Ratings on page 30 may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at http://www.silabs.com/support/quality/pages/default.aspx.

Table 4.19. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Мах	Unit
Ambient Temperature Under Bias	T _{BIAS}		-55	125	°C
Storage Temperature	T _{STG}		-65	150	°C
Voltage on VDD	V _{DD}		GND-0.3	4.2	V
Voltage on VIO ²	V _{IO}		GND-0.3	V _{DD} +0.3	V
Voltage on I/O pins or RSTb, excluding		V _{IO} > 3.3 V	GND-0.3	5.8	V
P2.0-P2.3 (QFN24 and QSOP24) or P3.0-P3.3 (QFN32 and QFP32)		V _{IO} < 3.3 V	GND-0.3	V _{IO} +2.5	V
Voltage on P2.0-P2.3 (QFN24 and QSOP24) or P3.0-P3.3 (QFN32 and QFP32)	V _{IN}		GND-0.3	V _{DD} +0.3	V
Total Current Sunk into Supply Pin	I _{VDD}		_	400	mA
Total Current Sourced out of Ground Pin	I _{GND}		400	_	mA
Current Sourced or Sunk by any I/O Pin or RSTb	I _{IO}		-100	100	mA
Operating Junction Temperature	TJ	T _A = -40 °C to 105 °C	-40	130	°C

Note:

1. Exposure to maximum rating conditions for extended periods may affect device reliability.

2. In certain package configurations, the VIO and VDD supplies are bonded to the same pin.

5.2 Debug

The diagram below shows a typical connection diagram for the debug connections pins. The pin sharing resistors are only required if the functionality on the C2D (a GPIO pin) and the C2CK (RSTb) is routed to external circuitry. For example, if the RSTb pin is connected to an external switch with debouncing filter or if the GPIO sharing with the C2D pin is connected to an external circuit, the pin sharing resistors and connections to the debug adapter must be placed on the hardware. Otherwise, these components and connections can be omitted.

For more information on debug connections, see the example schematics and information available in AN127: "Pin Sharing Techniques for the C2 Interface." Application notes can be found on the Silicon Labs website (http://www.silabs.com/8bit-appnotes) or in Simplicity Studio.

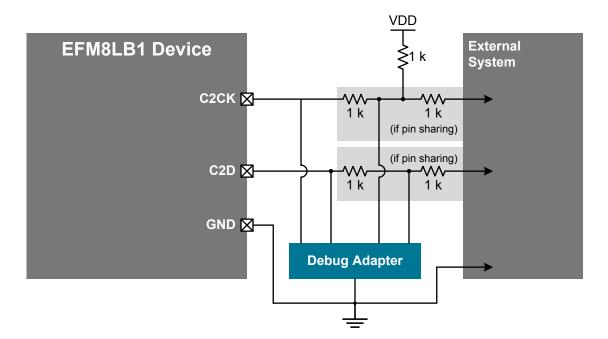


Figure 5.2. Debug Connection Diagram

5.3 Other Connections

Other components or connections may be required to meet the system-level requirements. Application Note AN203: "8-bit MCU Printed Circuit Board Design Notes" contains detailed information on these connections. Application Notes can be accessed on the Silicon Labs website (www.silabs.com/8bit-appnotes).

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
23	P1.2	Multifunction I/O	Yes	P1MAT.2	ADC0.8
				CLU0A.13	CMP0P.8
				CLU1A.11	CMP0N.8
				CLU2B.10	
				CLU3A.12	
24	P1.1	Multifunction I/O	Yes	P1MAT.1	ADC0.7
				CLU0B.12	CMP0P.7
				CLU1B.10	CMP0N.7
				CLU2A.11	
				CLU3B.13	
25	P1.0	Multifunction I/O	Yes	P1MAT.0	ADC0.6
				CLU1OUT	CMP0P.6
				CLU0A.12	CMP0N.6
				CLU1A.10	CMP1P.1
				CLU2A.10	CMP1N.1
				CLU3B.12	
26	P0.7	Multifunction I/O	Yes	P0MAT.7	ADC0.5
				INT0.7	CMP0P.5
				INT1.7	CMP0N.5
				CLU0B.11	CMP1P.0
				CLU1B.9	CMP1N.0
				CLU3A.11	
27	P0.6	Multifunction I/O	Yes	P0MAT.6	ADC0.4
				CNVSTR	CMP0P.4
				INT0.6	CMP0N.4
				INT1.6	
				CLU0A.11	
				CLU1B.8	
				CLU3A.10	
28	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	
				CLU3B.11	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
30	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.9	
				CLU3A.9	
31	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
32	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	

7. QFN32 Package Specifications

7.1 QFN32 Package Dimensions

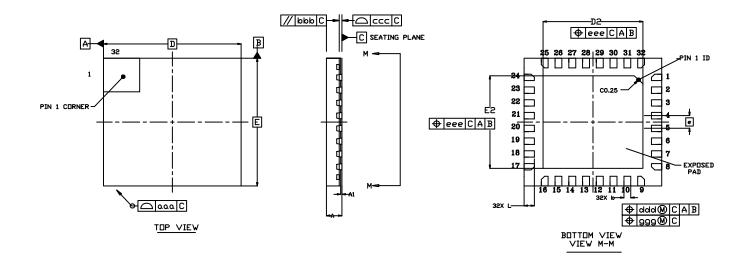


Figure 7.1. QFN32 Package Drawing

Dimension	Min	Тур	Мах
A	0.45	0.50	0.55
A1	0.00	0.035	0.05
b	0.15	0.20	0.25
D	4.00 BSC.		
D2	2.80	2.90	3.00
е	0.40 BSC.		
E	4.00 BSC.		
E2	2.80	2.90	3.00
L	0.20	0.30	0.40
ааа	—	_	0.10
bbb	—	_	0.10
ссс	—	_	0.08
ddd	—	—	0.10
eee	—	—	0.10
999	_	_	0.05

Table 7.1. QFN32 Package Dimensions

Dimension	Min	Max
Note:		
1. All dimensions shown are in millimeters	(mm) unless otherwise noted.	
2. Dimensioning and Tolerancing is per the	ANSI Y14.5M-1994 specification.	
3. This Land Pattern Design is based on th	e IPC-7351 guidelines.	
 All dimensions shown are at Maximum I cation Allowance of 0.05mm. 	Naterial Condition (MMC). Least Material Con	dition (LMC) is calculated based on a Fabri
 All metal pads are to be non-solder mas minimum, all the way around the pad. 	k defined (NSMD). Clearance between the so	older mask and the metal pad is to be 60 μ m
6. A stainless steel, laser-cut and electro-p	olished stencil with trapezoidal walls should b	be used to assure good solder paste release
7. The stencil thickness should be 0.125 m	m (5 mils).	
8. The ratio of stencil aperture to land pad	size should be 1:1 for all perimeter pads.	
9. A 2 x 2 array of 1.10 mm square openin	gs on a 1.30 mm pitch should be used for the	center pad.
10 A No Clean Turne 2 colder neets is read	mmondod	

- 10. A No-Clean, Type-3 solder paste is recommended.
- 11. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

7.3 QFN32 Package Marking

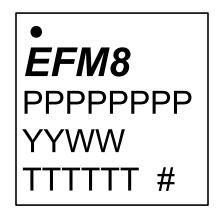


Figure 7.3. QFN32 Package Marking

The package marking consists of:

- PPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.
- # The device revision (A, B, etc.).

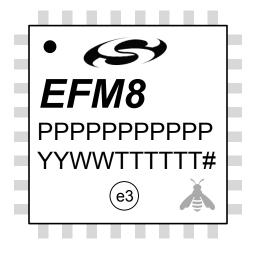
Dimension	Min	Тур	Мах
ааа		0.20	
bbb		0.20	
ССС		0.10	
ddd		0.20	
theta	0°	3.5°	7°
Note:			

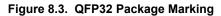
1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This drawing conforms to JEDEC outline MS-026.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.





The package marking consists of:

- PPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.
- # The device revision (A, B, etc.).

9. QFN24 Package Specifications

9.1 QFN24 Package Dimensions

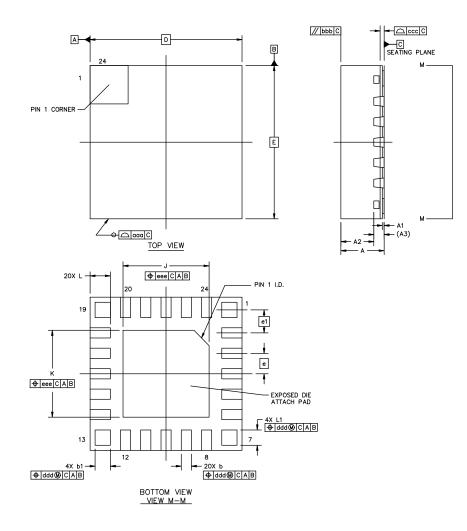


Figure 9.1. QFN24 Package Drawing

Table 9.1.	QFN24 Package Dimensions
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Dimension	Min	Тур	Мах	
A	0.8	0.85	0.9	
A1	0.00	—	0.05	
A2	—			
A3	0.203 REF			
b	0.15	0.2	0.25	
b1	0.25	0.3	0.35	
D	3.00 BSC			
E	3.00 BSC			

10.2 QSOP24 PCB Land Pattern

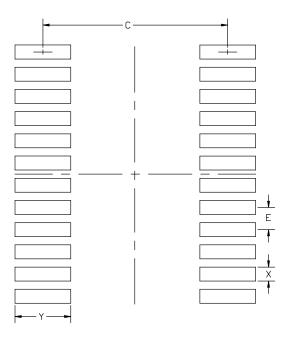


Figure 10.2. QSOP24 PCB Land Pattern Drawing

Table 10.2.	QSOP24 PCB Land Pattern Dimensions
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Dimension	Min	Мах	
С	5.20	5.30	
E	0.635 BSC		
X	0.30	0.40	
Y	1.50	1.60	

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This land pattern design is based on the IPC-7351 guidelines.

3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

5. The stencil thickness should be 0.125 mm (5 mils).

6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.

7. A No-Clean, Type-3 solder paste is recommended.

8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



Figure 10.3. QSOP24 Package Marking

The package marking consists of:

- PPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.
- # The device revision (A, B, etc.).

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